

February 1993 Revised April 2005

## 74LVX244

# Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

#### **General Description**

The LVX244 is an octal non-inverting buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

#### **Features**

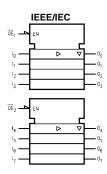
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

#### **Ordering Code:**

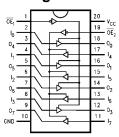
Order Number	Package Number	Package Description
74LVX244M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX244SJ	M20D	Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.

## **Logic Symbol**



#### **Connection Diagram**



#### **Pin Descriptions**

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output Enable Inputs
I <sub>0</sub> —I <sub>7</sub>	Inputs
O <sub>0</sub> -O <sub>7</sub>	Outputs

#### **Truth Tables**

Inp	outs	Outputs
OE <sub>1</sub>	I <sub>n</sub>	(Pins 12, 14, 16, 18)
L	L	L
L	Н	Н
Н	Х	Z

Inp	uts	Outputs
OE <sub>2</sub>	I <sub>n</sub>	(Pins 3, 5, 7, 9)
L	L	L
L	Н	Н
Н	X	Z

H = HIGH Voltage Level

L = LOW Voltage Level Z = High Impedance

#### **Absolute Maximum Ratings**(Note 1)

-0.5V to +7.0V Supply Voltage (V<sub>CC</sub>)

DC Input Diode Current  $(I_{IK})$ 

 $V_1 = -0.5V$ -20 mA DC Input Voltage (V<sub>I</sub>) -0.5V to 7V

DC Output Diode Current (I<sub>OK</sub>)

 $V_{O} = -0.5V$ -20 mA  $V_O = V_{CC} + 0.5V$ +20 mA DC Output Voltage (V<sub>O</sub>)

-0.5V to  $V_{CC} + 0.5V$ 

DC Output Source

or Sink Current (I<sub>O</sub>)  $\pm 25~\text{mA}$ 

DC V<sub>CC</sub> or Ground Current

 $(I_{CC} \text{ or } I_{GND})$ ±75 mA Storage Temperature (T<sub>STG</sub>) -65°C to +150°C

Power Dissipation 180 mW

## **Recommended Operating** Conditions (Note 2)

Supply Voltage ( $V_{CC}$ ) 2.0V to 3.6V 0V to 5.5V Input Voltage (V<sub>I</sub>) Output Voltage (Vo) 0V to V<sub>CC</sub> Operating Temperature (T<sub>A</sub>) -40°C to +85°C Input Rise and Fall Time ( $\Delta t/\Delta V$ ) 0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

#### **DC Electrical Characteristics**

Symbol	Parameter	V <sub>cc</sub>	T <sub>A</sub> = +25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions		
Cymbol		• 66	Min	Тур	Max	Min	Max	Oille	Conditions	
V <sub>IH</sub>	HIGH Level Input	2.0	1.5			1.5				
	Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V <sub>IL</sub>	LOW Level Input	2.0			0.5		0.5			
	Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V <sub>OH</sub>	HIGH Level Output	2.0	1.9	2.0		1.9			$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu\text{A}$ $I_{OH} = -50 \mu\text{A}$ $I_{OH} = -4 \text{ mA}$	
	Voltage	3.0	2.9	3.0		2.9		V	I <sub>OH</sub> = -50 μA	
		3.0	2.58			2.48			I <sub>OH</sub> = -4 mA	
V <sub>OL</sub>	LOW Level Output	2.0		0.0	0.1		0.1		$V_{IN} = V_{IH} \text{ or } V_{IL}  I_{OL} = 50  \mu\text{A}$	
	Voltage	3.0		0.0	0.1		0.1	V	$I_{OL} = 50 \mu A$	
		3.0			0.36		0.44		$I_{OL} = 4 \text{ mA}$	
l <sub>OZ</sub>	3-STATE Output	3.6			±0.25		±2.5	μА	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	
	Off-State Current								$V_{OUT} = V_{CC}$ or GND	
I <sub>IN</sub>	Input Leakage Current	3.6			±0.1		±1.0	μА	V <sub>IN</sub> = 5.5V or GND	
I <sub>CC</sub>	Quiescent Supply Current	3.6			4.0		40.0	μА	V <sub>IN</sub> = V <sub>CC</sub> or GND	

# Noise Characteristics (Note 3)

Symbol	Parameter	v <sub>cc</sub>	$T_A = 25^{\circ}C$		Units	C <sub>L</sub> (pF)	
			Тур	Limit	•		
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>		0.5	0.8	V	50	
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	-0.5	-0.8	V	50	
V <sub>IHD</sub>	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50	
V <sub>ILD</sub>	Maximum LOW Level Dynamic Input Voltage			0.8	V	50	

Note 3: Input  $t_r = t_f = 3 \text{ ns}$ 

# **AC Electrical Characteristics**

Symbol	Parameter	V <sub>CC</sub>	V <sub>CC</sub>		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions	
Cymbol		(V)	Min	Тур	Max	Min	Max	Oilles	Conditions
t <sub>PLH</sub>	Propagation Delay	2.7		6.1	11.4	1.0	13.5		C <sub>L</sub> = 15 pF
t <sub>PHL</sub>	Time			8.6	14.9	1.0	17.0	ns	C <sub>L</sub> = 50 pF
		$3.3 \pm 0.3$		4.7	7.1	1.0	8.5	113	C <sub>L</sub> = 15 pF
				7.2	10.6	1.0	12.0		C <sub>L</sub> = 50 pF
t <sub>PZL</sub>	3-STATE Output	2.7		7.1	13.8	1.0	16.5		C <sub>L</sub> = 15 pF,
t <sub>PZH</sub>	Enable Time								$R_L = 1 k\Omega$
				9.6	17.3	1.0	20.0		$C_L = 50 \text{ pF},$
								ns	$R_L = 1 k\Omega$
		$3.3 \pm 0.3$		5.5	8.8	1.0	10.5	110	C <sub>L</sub> = 15 pF,
									$R_L = 1 k\Omega$
				8.0	12.3	1.0	14.0		$C_L = 50 \text{ pF},$
									$R_L = 1 k\Omega$
t <sub>PLZ</sub>	3-STATE Output	2.7		11.6	16.0	1.0	19.0	ns	$C_L = 50 \text{ pF},$
$t_{PHZ}$	Disable Time	$3.3 \pm 0.3$		9.7	11.4	1.0	13.0	113	$R_L = 1 k\Omega$
t <sub>OSLH</sub>	Output to Output	2.7	•		1.5		1.5	ns	C <sub>L</sub> = 50 pF
toshl	Skew (Note 4)	3.3	•		1.5		1.5	113	

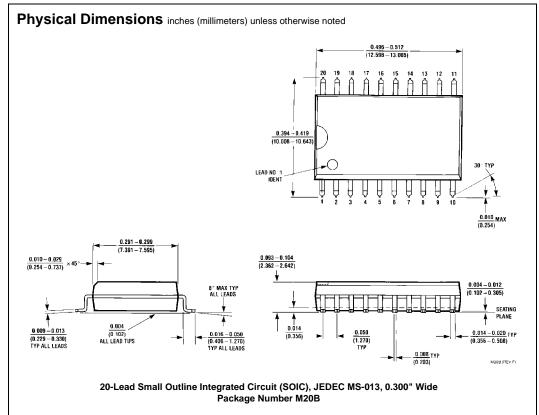
Note 4: Parameter guaranteed by design.  $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$ ,  $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$ 

# Capacitance

Symbol	Parameter		$T_A = +25^{\circ}C$		T <sub>A</sub> =-40°C to +85°C		Units
	i didiliotoi	Min	Тур	Max	Min	Max	00
C <sub>IN</sub>	Input Capacitance		4	10		10	pF
C <sub>OUT</sub>	Output Capacitance		6				pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)		19				pF

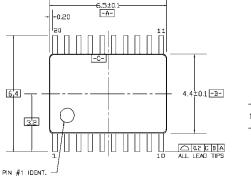
Note 5: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

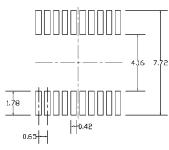
Average operating current can be obtained by the equation:  $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per bit)}}$ 



# Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 12.6±0.10 0.40 TYP --A-5.3±0.10 9.27 TYP 7.8 -B-3.9 0.2 C B A ALL LEAD TIPS 10 PIN #1 IDENT.-0.6 TYP 1.27 TYP LAND PATTERN RECOMMENDATION ALL LEAD TIPS SEE DETAIL A 0.1 C 1.8±0.1 -C-L <sub>0.15±0.05</sub> 0.15-0.25 -1.27 TYP 0.35-0.51 ⊕ 0.12 **(** C A DIMENSIONS ARE IN MILLIMETERS GAGE PLANE 0.25 NOTES: A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998. B. DIMENSIONS ARE IN MILLIMETERS. C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS. 0.60±0.15 SEATING PLANE 1.25 -M20DRevB1 DETAIL A Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide Package Number M20D

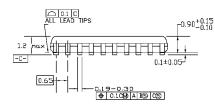
#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION

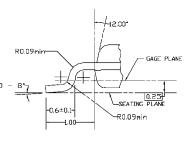
0.09-0.20



DIMENSIONS ARE IN MILLIMETERS



- A. CONFORMS TO JEDEC REGISTRATION ME-153, VARIATION AC, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.



SEE DETAIL A

DETAIL A

MTC20REVD1

# 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

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